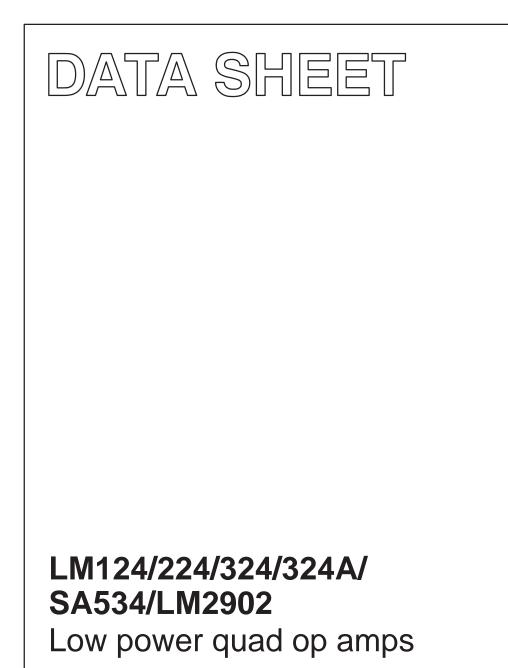
INTEGRATED CIRCUITS



Product data Supersedes data of 2001 Aug 03 File under Integrated Circuits, IC11 Handbook 2002 Jan 22





LM124/224/324/324A/ SA534/LM2902

DESCRIPTION

The LM124/SA534/LM2902 series consists of four independent, high-gain, internally frequency-compensated operational amplifiers designed specifically to operate from a single power supply over a wide range of voltages.

UNIQUE FEATURES

In the linear mode, the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage.

The unity gain crossover frequency and the input bias current are temperature-compensated.

FEATURES

- Internally frequency-compensated for unity gain
- Large DC voltage gain: 100 dB
- Wide bandwidth (unity gain): 1 MHz (temperature-compensated)
- Wide power supply range Single supply: 3 V_{DC} to 30 V_{DC} or dual supplies: ± 1.5 V_{DC} to ± 15 V_{DC}
- Very low supply current drain: essentially independent of supply voltage (1 mW/op amp at +5 V_{DC})
- Low input biasing current: 45 nA_{DC} (temperature-compensated)
- Low input offset voltage: 2 mV_{DC} and offset current: 5 nA_{DC}
- Differential input voltage range equal to the power supply voltage
- Large output voltage: 0V_{DC} to V_{CC}-1.5 V_{DC} swing

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
14-Pin Plastic Dual In-Line Package (DIP)	–55° C to +125 °C	LM124N	SOT27-1
14-Pin Plastic Small Outline (SO) Package	–25 °C to +85 °C	LM224D	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	–25 °C to +85 °C	LM224N	SOT27-1
14-Pin Plastic Small Outline (SO) Package	0 °C to +70 °C	LM324D	SOT108-1
14-Pin Plastic Thin Shrink Small Outline Package (TSSOP)	0 °C to +70 °C	LM324DH	SOT402-1
14-Pin Plastic Dual In-Line Package (DIP)	0 °C to +70 °C	LM324N	SOT27-1
14-Pin Plastic Small Outline (SO) Package	0 °C to +70 °C	LM324AD	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	0 °C to +70 °C	LM324AN	SOT27-1
14-Pin Plastic Small Outline (SO) Package	–40 °C to +85 °C	SA534D	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	–40 °C to +85 °C	SA534N	SOT27-1
14-Pin Plastic Small Outline (SO) Package	–40 °C to +125 °C	LM2902D	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	–40 °C to +125 °C	LM2902N	SOT27-1

PIN CONFIGURATION

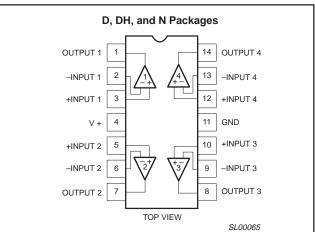


Figure 1. Pin configuration.

Product data

LM124/224/324/324A/ SA534/LM2902

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	32 or ±16	V _{DC}
V _{IN}	Differential input voltage	32	V _{DC}
V _{IN}	Input voltage	-0.3 to +32	V _{DC}
P _D	Maximum power dissipation, T _{amb} = 25 °C (still-air) ¹ N package D package DH package	1420 1040 762	mW mW mW
	Output short-circuit to GND one amplifier ² $V_{CC} < 15 V_{DC}$ and $T_{amb} = 25 °C$	Continuous	
I _{IN}	Input current (V _{IN} < -0.3 V) ³	50	mA
T _{amb}	Operating ambient temperature range LM324/324A LM224 SA534 LM2902 LM124	0 to +70 -25 to +85 -40 to +85 -40 to +125 -55 to +125	ဂိ ဂိ ဂိ
T _{stg}	Storage temperature range	-65 to +150	°C
T _{sld}	Lead soldering temperature (10 sec max)	230	°C

NOTES:

1. Derate above 25 $^\circ\text{C}$ at the following rates:

N package at 11.4 mW/°C

D package at 8.3 mW/°C

DH package at 6.1mW/°C

2. Short-circuits from the output to V_{CC}+ can cause excessive heating and eventual destruction. The maximum output current is approximately 40mA, independent of the magnitude of V_{CC}. At values of supply voltage in excess of +15 V_{DC} continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction.
3. This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input bias clamps. In addition, there is also lateral NPN parasitic transition and the output the proverties are to be the Versil (and the proverties and the proverties and the proverties are to be the Versil (and the proverties are to be the Versil).

transistor action on the IC chip. This action can cause the output voltages of the op amps to go to the V+ rail (or to ground for a large overdrive) during the time that the input is driven negative.

LM124/224/324/324A/ SA534/LM2902

DC ELECTRICAL CHARACTERISTICS

 V_{CC} = 5 V; T_{amb} = 25 °C, unless otherwise specified.

CVMDOI	DADAMETED	TEST CONDITIONS	ι	LM124/LM224		LM32	24/SA534	I/LM2902		
SYMBOL	PARAMETER	TEST CONDITIONS		Тур	Max	Min	Тур	Max		
N/		R _S = 0 Ω		±2	±5		±2	±7		
Vos	Offset voltage ¹	$R_S = 0 \Omega$, over temp.			±7			±9	mV	
$\Delta V_{OS} / \Delta T$	Temperature drift	$R_S = 0 \Omega$, over temp.		7			7		μV/°C	
	Input ourrept2	I _{IN} (+) or I _{IN} (–)		45	150		45	250	~^	
BIAS	Input current ²	I _{IN} (+) or I _{IN} (–), over temp.		40	300		40	500	nA	
$\Delta I_{BIAS} / \Delta T$	Temperature drift	Over temp.		50			50		pA/∘C	
1	Offset current	I _{IN} (+)–I _{IN} (–)		±3	±30		±5	±50	nA	
los	Olisei culleni	I _{IN} (+)–I _{IN} (–), over temp.			±100			±150		
$\Delta I_{OS} / \Delta T$	Temperature drift	Over temp.		10			10		pA/∘C	
V	Common-mode voltage	$V_{CC} \le 30 V$	0		V _{CC} -1.5	0		V _{CC} -1.5	v	
V _{CM}	range ³	$V_{CC} \le 30$ V; over temp.	0		V _{CC} -2	0		V _{CC} -2	v	
CMRR	Common-mode rejection ratio	V _{CC} = 30 V	70	85		65	70		dB	
V _{OUT}	Output voltage swing	$R_L = 2 k\Omega$, $V_{CC} = 30 V$, over temp.	26			26			V	
V _{OH}	Output voltage high	$\label{eq:RL} \begin{split} R_L &\leq 10 \text{ k}\Omega, \text{ V}_{CC} = 30 \text{ V},\\ \text{over temp.} \end{split}$	27	28		27	28		V	
V _{OL}	Output voltage low	$R_{L} \leq 10 \text{ k}\Omega$; over temp.		5	20		5	20	mV	
	O	$R_L = \infty$, $V_{CC} = 30$ V; over temp.		1.5	3		1.5	3		
Icc	Supply current	R _L = ∞; over temp.		0.7	1.2		0.7	1.2	2 mA	
	Large-signal voltage gain	$\label{eq:VCC} \begin{array}{l} V_{CC} = 15 \; V \; (\text{for large } V_O \; \text{swing}); \\ R_L \geq 2 \; k\Omega \end{array}$	50	100		25	100		V/mV	
A _{VOL}		V_{CC} = 15 V (for large V _O swing); R _L ≥ 2k Ω; over temp.	25			15				
	Amplifier-to-amplifier coupling ⁵	f = 1 kHz to 20 kHz, input referred		-120			-120		dB	
PSRR	Power supply rejection ratio	$R_{S} \leq 0 \Omega$	65	100		65	100		dB	
		V_{IN} + = +1 V, V_{IN} - = 0 V, V_{CC} = 15 V	20	40		20	40			
	Output current source	V_{IN} + = +1 V, V_{IN} - = 0 V, V_{CC} = 15 V, over temp.	10	20		10	20			
I _{OUT}		V_{IN} = +1 V, V_{IN} = 0 V, V_{CC} = 15 V	10	20		10	20		- mA	
	Output current sink	V_{IN} = +1 V, V_{IN} = 0 V, V_{CC} = 15 V, over temp. 5 8 5		8						
		V_{IN} = +1 V, V_{IN} = 0 V, V_{O} = 200 mV	12	50		12	50		μΑ	
I _{SC}	Short-circuit current ⁴		10	40	60	10	40	60	mA	
GBW	Unity gain bandwidth			1			1		MHz	
SR	Slew rate			0.3			0.3		V/µs	
V _{NOISE}	Input noise voltage	f = 1 kHz		40			40		nV/√Hz	
V _{DIFF}	Differential input voltage ³				V _{CC}			V _{CC}	V	

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DC ELECTRICAL CHARACTERISTICS (Continued)

V_{CC} = 5 V, T_{amb} = 25 °C unless otherwise specified.

		TEAT CONDITIONS		UNIT			
SYMBOL	PARAMETER	TEST CONDITIONS	Min	Тур	Max	UNIT	
M		R _S = 0 Ω		±2	±3		
V _{OS}	Offset voltage ¹	$R_{S} = 0 \Omega$, over temp.			±5	mV	
$\Delta V_{OS} / \Delta T$	Temperature drift	$R_{S} = 0 \Omega$, over temp.		7	30	μV/°C	
	lonut ourrent ²	I _{IN} (+) or I _{IN} (–)		45	100	~ ^	
BIAS	Input current ²	I _{IN} (+) or I _{IN} (-), over temp.		40	200	nA	
ΔΙ _{ΒΙΑS} /ΔΤ	Temperature drift	Over temp.		50		pA/°C	
	Offeet eurrent	I _{IN} (+)–I _{IN} (–)		±5	±30	~ ^	
los	Offset current	I _{IN} (+)–I _{IN} (–), over temp.			±75	nA	
ΔΙ _{ΟS} /ΔΤ	Temperature drift	Over temp.		10	300	pA/°C	
V	Common mode veltage tange3	$V_{CC} \le 30 \text{ V}$	0		V _{CC} -1.5	V	
V _{CM}	Common-mode voltage range ³	$V_{CC} \le 30$ V, over temp.	0		V _{CC} -2	V	
CMRR	Common-mode rejection ratio	$V_{CC} = 30 V$	65	85		dB	
V _{OUT}	Output voltage swing	$R_L = 2 \text{ k}\Omega$, $V_{CC} = 30 \text{ V}$; over temp.	26			V	
V _{OH}	Output voltage high	$R_L \leq$ 10 kΩ, V_{CC} = 30 V; over temp.	27	28		V	
V _{OL}	Output voltage low	$R_L \le 10 \ k\Omega$, over temp.		5	20	mV	
		$R_L = \infty$, $V_{CC} = 30$ V, over temp.		1.5	3	mA	
Icc	Supply current	$R_L = \infty$, over temp.		0.7	1.2	mA	
		V_{CC} = 15 V (for large V _O swing), R _L ≥ 2 kΩ	25	100		V/mV	
A _{VOL}	Large-signal voltage gain	V_{CC} = 15 V (for large V _O swing), R _L \ge 2k Ω , over temp.	15			V/mV	
	Amplifier-to-amplifier coupling ⁵	f = 1 kHz to 20 kHz, input referred		-120		dB	
PSRR	Power supply rejection ratio	$R_S \le 0 \Omega$	65	100		dB	
		V _{IN} + = +1 V, V _{IN} - = 0 V, V _{CC} = 15 V	20	40		mA	
	Output current source	V_{IN} + = +1 V, V_{IN} - = 0 V, V_{CC} = 15 V, over temp.	10	20		mA	
IOUT		V _{IN} -= +1 V, V _{IN} + = 0 V, V _{CC} = 15 V	10	20		mA	
	Output current sink	V_{IN} -=+1 V, V_{IN} +=0 V, V_{CC} =15 V, over temp.	5	8		mA	
		V _{IN} -=+1 V, V _{IN} +=0 V, V _O =200 mV	12	50		μA	
I _{SC}	Short-circuit current ⁴		10	40	60	mA	
V _{DIFF}	Differential input voltage ³			1	V _{CC}	V	
GBW	Unity gain bandwidth			1		MHz	
SR	Slew rate			0.3		V/µs	
V _{NOISE}	Input noise voltage	f = 1 kHz		40		nV/√Hz	

NOTES:

1. $V_{O} \approx 1.4 V_{DC}$, $R_{S} = 0 \Omega$ with V_{CC} from 5 V to 30 V and over full input common-mode range (0 V_{DC} + to V_{CC} –1.5 V). 2. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.

3. The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common-mode voltage range is V_{CC} –1.5, but either or both inputs can go to +32 V without damage. 4. Short-circuits from the output to V_{CC} can cause excessive heating and eventual destruction. The maximum output current is approximately

40 mA independent of the magnitude of V_{CC}. At values of supply voltage in excess of +15 V_{DC}, continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.

5. Due to proximity of external components, insure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of coupling increases at higher frequencies.

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EQUIVALENT CIRCUIT

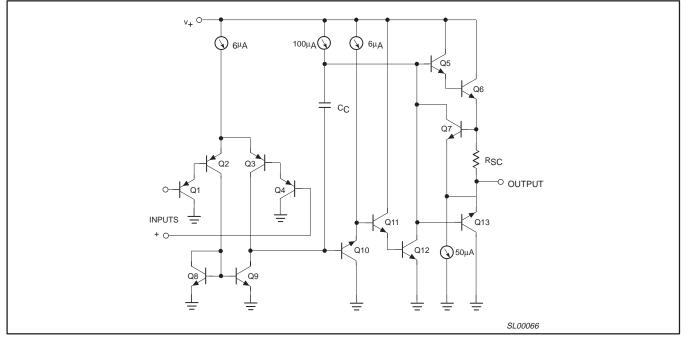


Figure 2. Equivalent circuit.

LM124/224/324/324A/ SA534/LM2902

TYPICAL PERFORMANCE CHARACTERISTICS

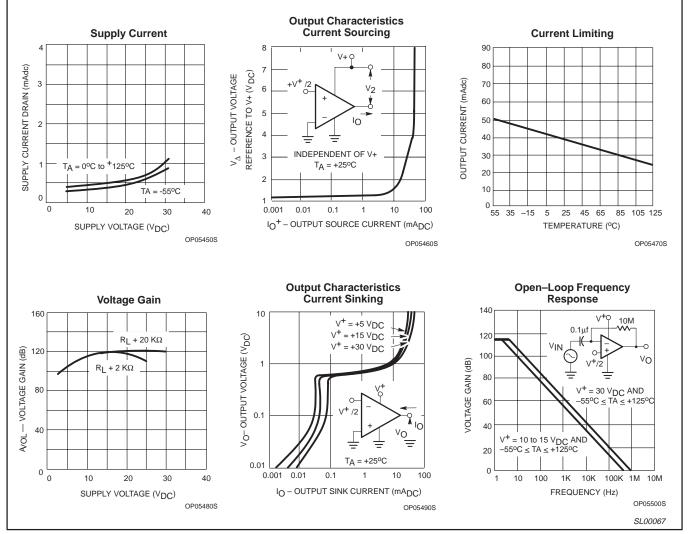


Figure 3. Typical Performance Characteristics

LM124/224/324/324A/ SA534/LM2902

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

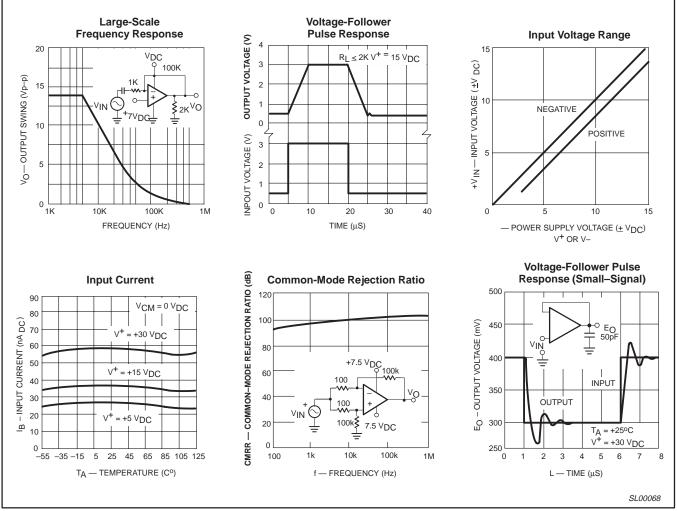


Figure 4. Typical Performance Characteristics (cont.)

TYPICAL APPLICATIONS

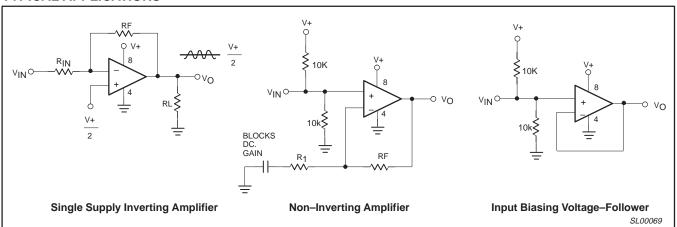
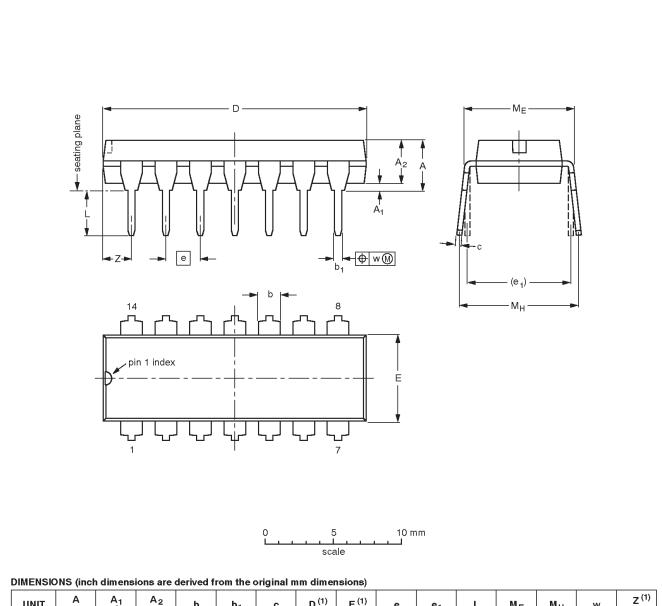


Figure 5. Typical Applications

DIP14: plastic dual in-line package; 14 leads (300 mil)



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	с	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	Μ _E	М _Н	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

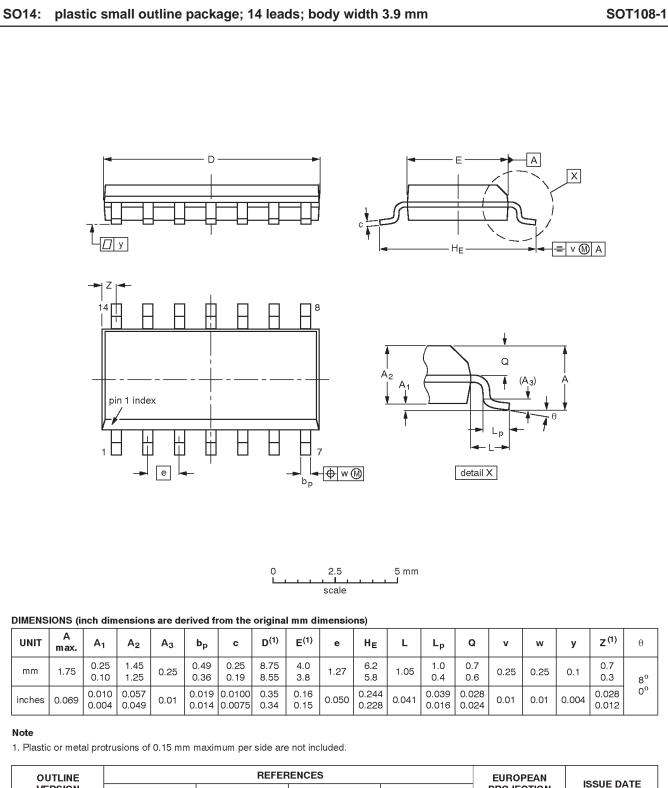
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN				
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE		
SOT27-1	050G04	MO-001	SC-501-14			-95-03-11 99-12-27		

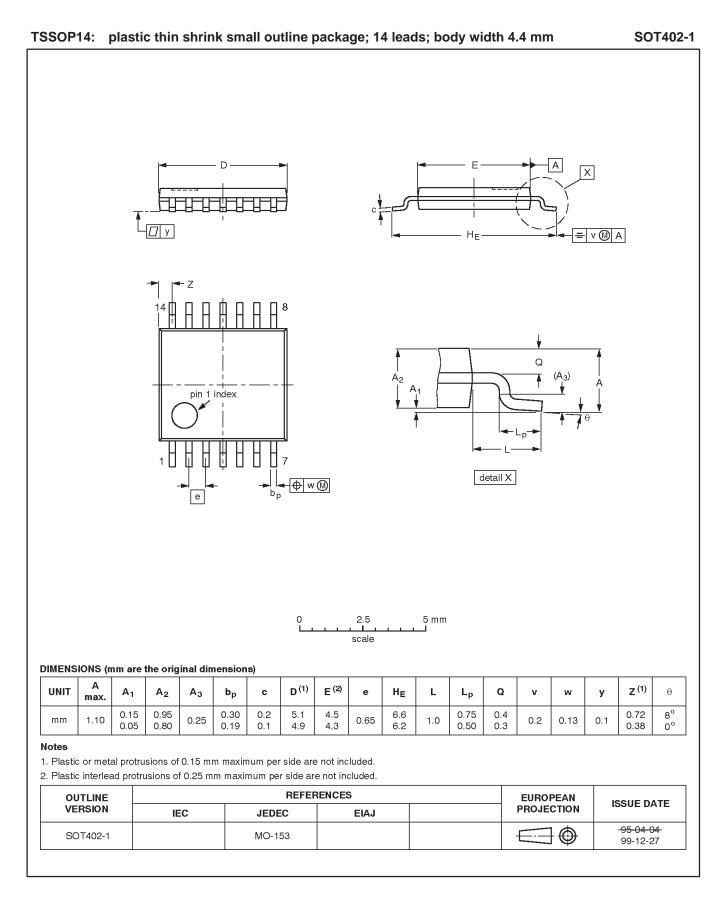
SOT27-1

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Data sheet status ^[1]	Product status ^[2]	Definitions
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0 27 24825

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